Chapter 3

Application of TiO$_2$ Nanotubes Gas Sensors in Online Monitoring of SF$_6$ Insulated Equipment

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Additional information is available at the end of the chapter

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Abstract

Titanium dioxide nanotube arrays (TNTAs) are a typical three-dimensional nanomaterial. TNTA has rich chemical and physical properties and low manufacturing costs. Thus, TNTA has broad application prospects. In recent years, research has shown that because of its large specific surface area and nanosize effect, the TNTAs have an enormous potential for development compared with other nanostructure forms in fields such as light catalysis, sensor, and solar batteries. TNTAs have become the hotspot of international nanometer material research. The tiny gas sensor made from TNTA has several advantages, such as fast response, high sensitivity, and small size. Several scholars in this field have achieved significant progress. As a sensitive material, TNTA is used to test O$_2$, NO$_2$, H$_2$, ethanol, and other gases. In this chapter, three SF$_6$ decomposed gases, namely SO$_2$, SOF$_2$ and SO$_2$F$_2$, are chosen as probe gases because they are the main by-products in the decomposition of SF$_6$ under PD. Then, the adsorption behaviors of these gases on different anatase (101) surfaces including intrinsic, Pt-doped and Au-doped, are studied using the first principles density functional theory (DFT) calculations. The simulation results can be used as supplement for gas-sensing experiments of TNTA gas sensors. This work is expected to add insights into the fundamental understanding of interactions between gases and TNTA surfaces for better sensor design.

Keywords: SF$_6$ decomposed gas, anatase TiO$_2$ surface, metal doping, adsorption, sensing mechanism, density functional theory

1. Introduction of titanium nanotubes

TiO$_2$ nanotubes are typically one-dimensional material, which has a wealth of physical and chemical properties and low production cost, and therefore, it bears a broad application
prospects [1, 2]. In particular, recent studies show that, due to large specific surface area and nanosize effect, compared with other forms of nanostructures, TiO$_2$ nanotubes show great potential for development in photocatalysis, sensors, solar cells and other areas [1, 3, 10]. It has become the research focus of nanomaterials internationally [1, 4–9]. The particular photocatalytic properties of TiO$_2$ under UV irradiation can degrade pollutants and reduce desorption time, thus extending the lifetime of sensors that based on TiO$_2$, which provides more opportunity for the development of high-quality new sensors.

1.1. Properties of titanium nanotubes

TiO$_2$ is one common type of N semiconductor oxide, of which the outer electron distribution is 3d$^2$4s$^2$. The molecular structure of TiO$_2$ belongs to flash zinc crystal lattice. Its structural center, Ti atom, is surrounded by six oxygen atoms, forming an octahedral structure which coordination number is 6. TiO$_2$ outer layer of 3d electronics is not active and 4 valence electrons of it form a covalent bond with O atom. From the above, we can know that the chemical properties of TiO$_2$ are very stable. It cannot dissolve in most acid, such as hydrochloric acid, nitric acid and dilute sulfuric acid, except concentrated sulfuric acid and hydrofluoric acid. The band gap of TiO$_2$ is approximately 3.2 eV. Its electrical conductivity is extremely low at room temperature. Even at high temperature, it only has a small conductivity. So its resistance is very big. We can almost see TiO$_2$ as an insulator. TiO$_2$’s conductance is achieved by activating the exciting electrons on the additional energy level to the conduction band. The additional level can be introduced from defects and impurities in TiO$_2$. So the types and quantities of these defects and impurities determine the TiO$_2$ conductivity type. Therefore, some methods may be employed to form a certain type of defect and impurity level or defect levels in the band gap to change the conductive properties of TiO$_2$.

There are three TiO$_2$ polymorphs in nature: rutile, anatase and brookite. Anatase and rutile structures are most widely used. Although rutile and anatase TiO$_2$ crystalline belong to the same tetragonal, but they have two different lattices. And thus, the X-ray images are different.

Anatase TiO$_2$ XRD diffraction angle 2θ is located in 25.5°, and rutile TiO$_2$ XRD diffraction angle 2θ is located in 27.5°. Rutile TiO$_2$ crystal forms a titanium atom in the lattice center, surrounded by six oxygen atoms which are located in octahedral edges and corners, and a cell composed of two moleculars is the most stable crystal structure. Anatase TiO$_2$ crystal form is composed of four TiO$_2$ molecules in a crystal cell, which is stable at low temperature. When the temperature reaches 610°C, it gradually transforms into rutile, and its transformation accelerated rapidly at 730°C, and it can transform into rutile completely at 915°C. Plate titanium ore TiO$_2$ crystal form, belonging to orthorhombic system, is a cell composed of six TiO$_2$ moleculars, which is an unstable crystal form that transforms into rutile type when the temperature is higher than 650°C. Figure 1 is the schematic diagram for the three kinds of morphology of crystalline structure of TiO$_2$.

Plate titanium ore crystal form belongs to the metastable phase, and thus its structure is unstable, which is therefore rarely used in industrial production. Anatase and rutile belong to the same crystal system, but the atomic arrangement of rutile is compact, so its relative density as
1.2. Preparation method of titanium nanotubes

Currently, there are three types of the method for preparing TiO\textsubscript{2} nanotubes, namely chemical template method, electrochemical method and hydrothermal method.

1.2.1. Chemical template method

The chemical template method involves assembling nanostructured primitive units into the porous template that forms nanotube structure. In the process of preparation of TiO\textsubscript{2} nanotube template, first, a porous alumina is prepared by anodizing, which is used as a template later, and then impregnates titanium-containing compound into the template by sol-gel method. After turning titanium-containing compound that entered into the porous alumina template into the metal oxide that possesses a template with a similar pore diameter and morphology of nanotube structure by a high temperature annealing process, porous alumina template is then dissolved with concentrated alkali. Since the metal oxide is not dissolved in concentrated alkali, metal oxide nanotubes such as TiO\textsubscript{2} nanotubes can be obtained, which have similar pore morphology to porous alumina template after washing by water. Martin et al. [11–13] successfully prepared nanotubes of TiO\textsubscript{2}, Co\textsubscript{3}O\textsubscript{4}, MnO\textsubscript{2}, WO\textsubscript{3} and ZnO and other metal oxides using this method.

1.2.2. Electrochemical method (anodic oxidation method)

Anodic oxidation method uses metal as an anode. Under the influence of applied electric field and electrolyte solution, electrochemical oxidation of the metal appears. Thereby a metal oxide film is produced on the surface of a metal. The formed metal oxide film will gradually dissolve because of the chemical reaction caused by the response plasma in electrolyte solution. The regional of chemical dissolution of metal oxide film is in nanoscale level. Therefore, when the speed of producing metal oxide by electric film dissolution is larger than the rate of chemical...
dissolution, the oxide film is ever thickening and accompanied by numerous nanopore deepening constantly caused by chemical dissolution. When the speed of producing metal oxide by electric film dissolution is equal to the rate of chemical dissolution, the thickness of the oxide film and the depth of the nanopores do not change. At this time, a certain thickness oxide film with a metal oxide nanotube structure is ready. With the controlling of the different experimental conditions in certain electrolyte, we can prepare TNTA with different diameters and lengths by anodizing. In 2001, Grimes \[14\] first reported that the TNTA with ordered arrangement can be obtained at room temperature after directly anodizing for pure titanium sheet in an HF aqueous solution. Grimes \[10\] studied the growth of the nanotubes changes under different conditions of the anodizing electrolyte. The length of the nanotubes can be increased when the electrolyte exhibits weak acid. In the case of organic phase electrolyte, the tube walls are smoother and the tube length can also reach about a hundred micrometers.

1.2.3. Hydrothermal method

Since the hydrothermal preparation method is simple and cheap, it is widely used in industrial production processes. TiO$_2$ nanotubes prepared by this way are typically entwined and disorderly: first preparing TiO$_2$ nanoparticles, and then mixing the nanoparticles with strong alkali solution. Under conditions of high temperature and pressure, monolayer nanosheets curl of TiO$_2$ in the alkali solution appears. Its formation mechanism is similar to that of multi-walled carbon nanotubes; it is a combination process from one-dimensional to two-dimensional and three-dimensional. After forming the TiO$_2$ nanotubes, the product is neutralized by weak acid to neutralize the strong alkaline solution, and centrifuging it to get powdery TiO$_2$ nanotubes. Using this method, Kasu’s team processed the TiO$_2$ nanoparticles powder and NaOH solution at 110°C, then washed the reactants with water and hydrochloric acid and finally get TiO$_2$ nanotubes \[15\].

2. Intrinsic and surface-modified TiO$_2$ nanotubes gas sensors

2.1. Intrinsic TiO$_2$ nanotubes gas sensors

2.1.1. Investigation of gas-sensing simulation of intrinsic TiO$_2$ nanotubes

Three SF$_6$ decomposed gases, namely SO$_2$, SOF$_2$, and SO$_2$F$_2$, are chosen as probe gases because they are the main by-products in the decomposition of SF$_6$ under PD. The adsorption behaviors of these gases on an anatase (101) surface are studied using the first principles density functional theory (DFT) calculations.

2.1.1. Adsorption models and calculation methods

The optimal lattice size of bulk anatase given in MS is $3.776 \times 3.776 \times 9.486$ Å$^3$, which is very small compared with the size of a single TiO$_2$ nanotube. Thus, the gas molecules adsorbed in a small area of the TNTAs surface are simulated, and the nanotube-array structure is not taken into account. The prepared TNTAs are calcined at a high temperature in an oxygen-rich
environment, and oxygen atoms should occupy the oxygen vacancies on the TNTAs surface [16]. The phenomenon is consistent with the findings that many thermodynamically stable (101) facets dominate the surface of most anatase nanocrystals [17]. Therefore, the gas-array interaction can be properly simulated on the anatase (101) surface.

Periodic boundary model is adopted in this work, and the 2 × 2 supercell of the anatase (101) surface is created in MS, as shown in Figure 2. The size of the supercell is 10.88 × 7.55 × 17.84 Å³. In order to avoid the interaction between adjacent cells which is induced by the periodic boundary condition, the vacuum layer above surface is about 12 Å. The atoms on the bottom layer are fixed, and the structure of the supercell is optimized.

The generalized gradient approximation (GGA) exchange-correlation function parameterized by Perdew, Burke, and Ernzerhof [18] is employed for the electron-electron exchange and correlation interactions. Moreover, the double numerical basis set plus polarization functions (DNP) [19, 20] are used. All optimized structures are obtained with a precision of 1 × 10⁻⁵ Ha for energy, 2 × 10⁻³ Ha/Å for force, and 5 × 10⁻³ Å for displacement. The convergence threshold for the electronic self-consistent field is set to 1 × 10⁻⁶ Ha. A Fermi smearing of 5 × 10⁻⁴ Ha is used. To speed up the convergence and reduce calculation time, the DIIIS (direct inversion in an iterative subspace) is used at the same time. The Brillouin zone is sampled at 2 × 3 × 1 k-mesh [21]. All spin-unrestricted DFT calculations are performed using the Dmol³ package [19, 20].

The band gap is 2.16 eV, which is closer to other simulation results [22, 23] but smaller than the experimental gap (3.24 eV [24]). The reason for this is the well-known deficiency of the GGA arithmetic [25] in which DFT maps the problem of N interacting electrons onto a system of N non-interacting fictitious particles. Therefore, the calculation scheme is effective, and the results and conclusions are reasonably reliable.
The active atoms of the anatase (101) surface are Ti\textsubscript{5c} and O\textsubscript{2c}, as shown in Figure 2. Figure 3 shows band structure of the optimized supercell. To find the most stable adsorption structures, the three gas molecules should approach the active atoms on the surface in different orientations and behaviors. Figure 4 shows the most stable adsorption structures of the three gas molecules.

2.1.1.2. Adsorption parameters and analysis

The gas-surface interaction can be described using the adsorption energy \( E_{\text{ad}} \) defined as

\[
E_{\text{ad}} = E_{\text{surf/gas}} - E_{\text{gas}} - E_{\text{surf}}
\]

where \( E_{\text{gas}} \) is the energy of one isolated gas molecule in its optimized structure, \( E_{\text{surf}} \) is the total energy of the TiO\textsubscript{2} structure, and \( E_{\text{surf/gas}} \) is the total energy of the adsorption structure \([1]\). \( E_{\text{ad}} < 0 \) means that the adsorption process is exothermic and spontaneous.

The change in charge distribution should be known. Therefore, the charge transfer \( q \) is calculated using the Mulliken population analysis and is defined as the charge variation of isolated gas molecules when it is adsorbed \([1]\). A positive \( q \) value means that the charge is transferred from the molecule to the anatase surface. The binding distance \( d \) is defined as the nearest distance between the molecule and the surface. The calculated adsorption parameters are shown in Table 1.

The adsorption energies are negative, indicating that the adsorptions are exothermic and spontaneous. The values of energy released in the adsorptions are SO\textsubscript{2} > SOF\textsubscript{2} > SO\textsubscript{2}F\textsubscript{2} and all are small (<0.6 eV). This finding indicates that the molecules of the three gases are physisorbed, not chemisorbed, on the anatase (101) surface. Thus, gas molecules cannot effectively be adsorbed.

Figure 3. Band structure of the optimized supercell.
on TNTAs at room temperature because of the small adsorption energy, indicating that the experimental responses of the three gases may also be very small at room temperature. When the temperature is high, the $\text{Ti}_5\text{O}_{2c}$ bonds will be stretched with the increased temperature, and the interactions between the molecules and surface become stronger. Under this condition, the molecules can be chemisorbed on the surface, which can explain the high responses in the sensing experiment. The adsorption energy of $\text{SO}_2$ is the largest of the three gases, which shows that the adsorption of $\text{SO}_2$ is the strongest; it is firmly absorbed and difficult to desorb.

The three gases all behave as charge donors. The charge transfer of $\text{SO}_2$ is more than twice than that of $\text{SOF}_2$, and for $\text{SO}_2\text{F}_2$, it is only 0.008 e. This finding indicates that $\text{SO}_2$ can provide more electrons to the surface and that the surface has a better sensitivity to $\text{SO}_2$.

The highest occupied molecular orbital (HOMO) energy level and lowest unoccupied molecular orbital (LUMO) energy level of the three gas molecules and of the anatase (101) surface are calculated according to molecular orbital theory. By analyzing the HOMO and LUMO, whether the gases easily interact with the anatase (101) surface can be estimated. $E_1$ and $E_2$ are defined as follows:

$$
E_1 = \left| E_{\text{HOMO(TiO}_2)} - E_{\text{LUMO(gas)}} \right|
$$

$$
E_2 = \left| E_{\text{LUMO(TiO}_2)} - E_{\text{HOMO(gas)}} \right|
$$

If $E_1$ is small, the charge is more easily transferred to the gas molecules from the surface. If $E_2$ is small, the charge is more easily transferred to the surface from the gas molecules. The calculated $E_{\text{HOMO}}$, $E_{\text{LUMO}}$, $E_1$, and $E_2$ are listed in Table 2.
Both the \( E_1 \) and \( E_2 \) of \( \text{SO}_2 \) are smaller than those of the other two gases. This finding shows that \( \text{SO}_2 \) easily interacts with the anatase (101) surface and that the charge transfer is also the easiest between them. \( \text{SO}_2 \) interacting with the surface is relatively difficult. Here, we also find that the anatase (101) surface is more sensitive to \( \text{SO}_2 \) than to \( \text{SOF}_2 \) and the sensitivity of the surface to \( \text{SOF}_2 \) is better than that to \( \text{SO}_2 \).

The energy gap of the adsorption structure can be calculated through the energy levels of the HOMO and LUMO defined as \( E_g \):

\[
E_g = | E_{\text{HOMO}} - E_{\text{LUMO}} |	ag{2}
\]

The energy gap width determines how much energy an electron needs to jump into the LUMO from the HUMO. The wider the gap, the more energy is required and the more difficult it is for electrons to transfer between the valence band (VB) and the conduction band (CB). Table 3 shows the energy gaps. The adsorption of \( \text{SO}_2 \) on the anatase (101) surface reduces the energy gap width and improves the electron transfer of the surface. However, the adsorption of \( \text{SOF}_2 \) and \( \text{SO}_2 \text{F}_2 \) cannot do so. Therefore, TNTAs are much more responsive to \( \text{SO}_2 \) gas than to \( \text{SOF}_2 \) and \( \text{SO}_2 \text{F}_2 \).

The molecular structures of the gases are also analyzed based on valence bond theory (VBT) combined with molecular orbital theory. A three-center four-electron pi bond exists in the \( \text{SO}_2 \) molecule, and the pi bond contains five orbitals that are hybridized by a 3p orbital, two 3d orbitals in the S atom, and a 3p orbital in each O atom. This finding indicates that the pi bond consists of some 3d orbitals. Four electrons occupy the two lower orbitals (i.e., HOMO and HOMO-1) of the pi bond, and the middle orbital of the pi bond is unoccupied (LUMO). However, the d-p pi bond exists between the S atom and the O atom in the \( \text{SOF}_2 \) and \( \text{SO}_2 \text{F}_2 \) molecules. The S atom in \( \text{SOF}_2 \) has one lone pair of electrons, but not the \( \text{SO}_2 \text{F}_2 \). Therefore, the

<table>
<thead>
<tr>
<th>System</th>
<th>( E_{\text{HOMO}}/\text{eV} )</th>
<th>( E_{\text{LUMO}}/\text{eV} )</th>
<th>( E_1/\text{eV} )</th>
<th>( E_2/\text{eV} )</th>
</tr>
</thead>
<tbody>
<tr>
<td>( \text{TiO}_2 )</td>
<td>-7.257</td>
<td>-5.093</td>
<td>/</td>
<td>/</td>
</tr>
<tr>
<td>( \text{SO}_2 )</td>
<td>-8.000</td>
<td>-4.669</td>
<td>2.587</td>
<td>2.917</td>
</tr>
<tr>
<td>( \text{SOF}_2 )</td>
<td>-8.536</td>
<td>-3.072</td>
<td>4.185</td>
<td>3.453</td>
</tr>
<tr>
<td>( \text{SO}_2 \text{F}_2 )</td>
<td>-9.145</td>
<td>-2.628</td>
<td>4.628</td>
<td>4.062</td>
</tr>
</tbody>
</table>

Table 2. Energy frontier molecular orbital and the energy difference.

Table 3. Energy gaps of the adsorption structures and structures without adsorption.
SO$_2$F$_2$ molecule is more stable than the SOF$_2$ molecule. Moreover, the activities of the gas molecules can be compared by obtaining the difference between $E_{HOMO}$ and $E_{LUMO}$. Table 4 shows $\Delta E$, which is defined as $\Delta E = E_{LUMO\,(gas)} - E_{HOMO\,(gas)}$. Based on the VBT analysis and the data in Table 4, the pi bond in SO$_2$ is more active than the d-p pi bond in SOF$_2$ and SO$_2$F$_2$. Moreover, SO$_2$ is easy to interact with the anatase (101) surface.

To investigate the influence of adsorbed gas molecules on the electronic property of the anatase (101) surface, the total density of states (TDOS) of the adsorption system and the projected density of states (PDOS) of adsorbed gas molecules calculated using MS are given in Figure 5. The Fermi level is aligned at zero. As shown in Figure 5, when the molecules of the three gases are adsorbed on the surface, the Fermi levels of those still on top of the VB change little. This finding indicates the formation of a depletion region on the surface, and only a few charge carriers are present in this region. Therefore, the surface presents high resistivity.

The TDDSs of the SO$_2$, SOF$_2$, and SO$_2$F$_2$ adsorption systems remain nearly unchanged compared with the system without adsorption, which indicates that the adsorbed SO$_2$, SOF$_2$, and SO$_2$F$_2$ induce little change to the electronic property of the (101) surface. An unapparent density peak of around 2.8 eV exists in the PDOS of SO$_2$. On the other hand, the adsorbed SO$_2$ induces noticeable change to the electronic property of the (101) surface. The SO$_2$ adsorption introduces an impurity state near the CB, as shown in Figure 6, resulting in a narrowing of the band gap (which changes from 2.161 to 1.527 eV). The unoccupied impurity state is a surface state of the anatase (101) surface, which can capture or release electrons or form a composite center, improving the conductive performance of the surface. The PDOSs of p orbitals that contribute to the impurity state and the orbitals that contain the 3p orbital of the S atom and the 2p orbital of the O atom (near the surface in Figure 4) are shown in Figure 7.

### 2.1.2. Preparation and surface characterization of intrinsic TiO$_2$ nanotubes

The present study generated a TNTA by an anodic oxidation method using a two-electrode system [1]. A platinum metal piece was used as cathode, whereas a titanium piece was used as anode. The experimental processes are as follows: first, 0.5-mm-thick Ti foil (area of 0.8 cm × 2.0 cm and purity of 99.94%) was burnished with sandpaper, soaked in 30% HCl solution, and heated to 80°C for 20 min to remove the surface oxidation layer [1]. Then, the Ti pieces were cleaned by washing with deionized water. The clean Ti pieces acted as the anode, whereas the platinum pieces acted as the cathode in the two-electrode electrochemical electrolysis pool. Between the two electrodes, a constant 20 V of anodic oxidation was applied continuously for 2 h. The electrolyte concentration was 0.1 M HF solution, and the electrolyte pH value was tested using a Model 3000 pH meter [1]. Magnetic stirring was applied to ensure the uniformity of the Ti electrode surface electric current and temperature in the oxidation process and

<table>
<thead>
<tr>
<th>Gas</th>
<th>SO$_2$</th>
<th>SOF$_2$</th>
<th>SO$_2$F$_2$</th>
</tr>
</thead>
<tbody>
<tr>
<td>$\Delta E$/eV</td>
<td>3.330</td>
<td>5.464</td>
<td>6.517</td>
</tr>
</tbody>
</table>

Table 4. Difference between HOMO and LUMO.
reduce the influence of the double electric layer between the electrolyte and electrode interface [1]. After the reaction, the TNTA was cleaned by washing with deionized water, dried in air heated from 2°C/min to 500°C in a muffle furnace for 1 h, and then removed after the temperature dropped to room temperature [1].

Figure 5. The TDOS of adsorption systems and the PDOS of adsorbed gas molecules.

Figure 6. Band structure of the TiO$_2$-SO$_2$ adsorption system.

reduce the influence of the double electric layer between the electrolyte and electrode interface [1]. After the reaction, the TNTA was cleaned by washing with deionized water, dried in air heated from 2°C/min to 500°C in a muffle furnace for 1 h, and then removed after the temperature dropped to room temperature [1].
Figure 8 shows the scanning electron microscopy (SEM) images of the TNTAs. As observed from the SEM images, the TNTAs are highly ordered and directionally grown, the pipe diameter of which is about 80 nm, length is about 300 nm, and thickness is about 10 nm. The main effect of having an ordered structure is to further improve the area's effective adsorption area. The schematic diagram of TNTAs is shown in Figure 9.

Figure 10 shows the X-ray diffraction spectrum diagram of the TNTAs. The strong (101) facet peak of anatase (A in the figure) exists at $2\theta = 25.3^\circ$, and the weak strong (110) facet peak of rutile exists at $2\theta = 27.4^\circ$ (R in the figure). These findings indicate that TNTAs are mainly anatase, and a small amount of the rutile phase is observed.

2.1.2.1. Gas-sensing experiments of intrinsic TiO$_2$ nanotubes sensors

Figure 11 presents the detection test device for the TNTA sensor response measurement of the SF$_6$ decomposition products [1]. Shown in the figure are the following: (1) quartz glass tube; (2) thermal resistance probe; (3) carbon nanotube sensors; (4) ceramic heating slices; (5) vacuum form; (6) vacuum pump; (7) vent ducts; (8) terminals; (9) AC regulator; (10) temperature display apparatus; (11) impedance analyzer; (12) gas flow meter; and (13) inlet ducts [1].
The tested gases are SO$_2$, SOF$_2$, and SO$_2$F$_2$, which have a concentration of 50 μL/L, and N$_2$ is used as the carrier gas [26]. The response $R\%$ is defined as the relative variation of the sensor’s resistance: $(R_g - R_0)/R_0$, where $R_g$ is the resistance of the sensor to the relevant gas, and $R_0$ is pure
The factors that influenced the response are analyzed comparatively, and the sensing mechanism of the temperature characteristic curves is explained based on the simulation results.

The responses of TNTAs to the 50 μL/L gases are shown in Figure 12. At 20°C, the response of SO\(_2\) is slightly higher than that of SOF\(_2\) and SO\(_2\)F\(_2\), and the responses of SOF\(_2\) and SO\(_2\)F\(_2\) are both small. When the temperature is above 120°C, the response of SO\(_2\) is much higher than that of the two gases. The response of SOF\(_2\) is slightly higher than that of SO\(_2\)F\(_2\). This phenomenon matches the simulated findings. Therefore, the study concludes that the response R% depends on the impurity state introduced by the adsorbed gas molecule, and the band structure influences by the impurity state.

The sensing mechanism of temperature characteristic curves is analyzed first.

When the temperature is low, the adsorbed gas molecules can provide a number of electrons to the semiconductor surface or reduce the band gap of the semiconductor; the thermal excita-

![Figure 11. Detection test device for the TNTA sensor response measurement of SF\(_6\) decomposition products.](image1)

![Figure 12. Temperature characteristic curves of the responses of 50 μL/L gases.](image2)
tion of the semiconductor remains weak. The electron depletion region of the surface remains, and the electron concentration variation is small. All sensing responses are low when the temperature is low. Conversely, when the temperature increases, thermal excitation begins to play a main role, and more electrons in the valence band exit to the conduction band, producing more hole electron pairs and greatly increasing the electron concentration. The adsorption of the three gases then provides electrons onto the semiconductor surface, introduces the impurity states, and reduces the band gap. Thus, more excited electrons enter into the CB from the VB, and their sensing response becomes higher.

The reason for the changes in the temperature characteristic response of $\text{SO}_2$ as shown in the curve in Figure 12, is discussed. The gas response at a high temperature is positively related to the concentration of thermally excited electrons and the adsorption amount of gas molecules. The adsorption amount increases when the temperature increases. However, if the temperature is too high, the thermal motions of the gas molecules become aggressive and a number of adsorbed gas molecules break away from the surface, decreasing the adsorption amount. The electrons produced by thermal excitation grow exponentially with the increasing temperature. Thus, the temperature characteristic response increases with the increasing temperature at first and then remains nearly unchanged.

The responses of $\text{SO}_2$ and $\text{SOF}_2$ are then compared. When the temperature is about 200°C, the response of $\text{SOF}_2$ is much lower than that of $\text{SO}_2$, and it is not sensitive to the varying temperature. The impurity state introduced by $\text{SO}_2$ has a great impact on the band structure and the $\text{SO}_2$ has a higher response because the impurity state introduced by $\text{SOF}_2$ has little effect on the band structure. The thermal excitation is weak, and only a few electrons are exit to the CB through the impurity states under 20°C. Therefore, the impurity states of $\text{SO}_2$ and $\text{SOF}_2$ have little effect on the band structure. However, $\text{TSO}_2$ provides more electrons to the surface, and the response of $\text{SO}_2$ is slightly high.

Finally, the responses of $\text{SOF}_2$ and $\text{SO}_2\text{F}_2$ are compared. $\text{SOF}_2$ provides more electrons to the surface than $\text{SO}_2\text{F}_2$, but the responses of the two gases are both small because the impurity states induced by the two adsorbed gases have little influence on the band structure. The electron depletion region on the surface also influences the low responses. Considering the comparative analysis of $\text{SO}_2$ and $\text{SOF}_2$, it can be concluded that, if the impurity state introduced by adsorbed gas has a greater impact on the band structure, the electrons provided by adsorbed gas will have a relatively large influence on the response at low temperatures.

When the temperature is high, the response of $\text{SOF}_2$ is slightly higher than that of $\text{SO}_2\text{F}_2$. The unapparent density peak around 2.8 eV in the PDOS of $\text{SOF}_2$ has a certain effect on the band structure, and some electrons in the VB exit to the CB, which promotes the response.

The difference between the responses to 50 μL/L $\text{SOF}_2$ and $\text{SO}_2\text{F}_2$ is not obvious in Figure 12; thus, we discuss the concentration response curves of $\text{SOF}_2$ and $\text{SO}_2\text{F}_2$ at 200°C in Figure 13. In Figure 13, with increased concentration, the increase in $\text{SO}_2\text{F}_2$ response is relatively larger than that of the $\text{SOF}_2$ response because the impurity state introduced by the increase in $\text{SOF}_2$ has a greater impact on the band structure.
2.2. Pt-doped TiO₂ nanotubes sensors

The adsorptions of SO₂, SOF₂, and SO₂F₂ on Pt-modified anatase (101) surface are calculated, the effect of modified Pt on the adsorption behavior of gas molecules is analyzed, and the sensing mechanism of Pt-modified TNTA is also explained clearly [27]. In this study, we improve the sensing mechanism of Pt-modified TNTA and provide a theoretical basis for the detection of SF₆ decomposition components using the TNTA gas sensor [1, 28].

2.2.1. Investigation of gas-sensing simulation of Pt-doped TiO₂ nanotubes

2.2.1.1. Adsorption models and calculation methods

Figure 14 shows the adsorption structures of SO₂, SOF₂, and SO₂F₂ on the perfect (101) surface of Pt-modified anatase [1]. The adsorption parameters are shown in Table 5. Comparing the parameters in Table 5 [1] with the parameters in references [29, 30], we observed that the modified
Pt atom has a slight influence on the adsorptions of the three gases on the perfect surface near the Pt atom [1]. The energy values of the three gases adsorbed on the anatase perfect surface are all still <0.6 eV. The charges in the adsorptions are still transferred from the molecules to the surface, which reveals that the three adsorptions are physisorptions [1]. This finding indicates that the adsorption performance of the perfect (101) surface of the Pt-modified anatase to the three gases is nearly unchanged [1]. Figure 15 shows the DOS of the three adsorption structures [1]. We observed that the DOS is also nearly unchanged, and the state density near the Fermi level is mainly determined by the modified Pt atom. However, when the three gas molecules adsorb on the perfect (101) surface of the Pt-modified anatase, the conductivity of the surface is improved [1,29].

2.2.1.2. Adsorption parameters and analysis

Figure 16 shows the adsorption structures of SO$_2$, SOF$_2$ and SO$_2$F$_2$ on the modified Pt atom [1]. The adsorption parameters are shown in Table 6 [1]. When SO$_2$ is adsorbed, two situations, which depend on the initial structure, occur. One is the physisorption structure shown

<table>
<thead>
<tr>
<th>Adsorption site</th>
<th>Structure</th>
<th>Adsorption energy</th>
<th>Charge transfer</th>
<th>Bond distance</th>
</tr>
</thead>
<tbody>
<tr>
<td>Perfect surface of the Pt-modified anatase surface</td>
<td>SO$_2$–TiO$_2$(a)</td>
<td>-0.3606</td>
<td>0.0920</td>
<td>2.471</td>
</tr>
<tr>
<td></td>
<td>SOF$_2$–TiO$_2$(b)</td>
<td>-0.2811</td>
<td>0.0470</td>
<td>2.803</td>
</tr>
<tr>
<td></td>
<td>SO$_2$F$_2$–TiO$_2$(c)</td>
<td>-0.0692</td>
<td>0.0110</td>
<td>2.841</td>
</tr>
</tbody>
</table>

Table 5. Adsorption parameters of the three gases adsorbed on the perfect (101) surface of Pt-modified anatase.

Figure 15. TDOSs of the adsorption structures of SO$_2$, SOF$_2$, and SO$_2$F$_2$ on the perfect (101) surface of Pt-modified anatase and PDOSs of the three gases in these structures.
in Figure 16a whose adsorption energy is −0.2394 eV. The other is the chemisorption structure shown in Figure 16b whose adsorption energy is −1.1009 eV. When SOF₂ is adsorbed, the physisorption and chemisorption situations occur. The chemisorption structure is shown in Figure 16c. The Pt atom has a stronger adsorption to the S atom in SOF₂ than the O or F atom [1]. Thus, the SOF₂ molecule is more easily chemisorbed on the Pt atom with the S atom, rather than physisorbed with the O or F atom [1].

When SO₂F₂ is adsorbed, the adsorptions are mainly physisorptions, such as the structure shown in Figure 16d. In addition, in a few initial structures, one S–F bond of SO₂F₂ may break and SO₂F₂ would be chemisorbed on the Pt atom. Figure 17 shows the DOS of the three gases adsorbed on the Pt atom [1]. The adsorbed gas molecules contributed to the state density near the Fermi level, which changes the electronic distribution of the area around the modified Pt atom and influences the conductivity of this area [1].

Considering that the actual size of the modified Pt nanoparticle is larger than a single gas atom, and the conductivity of the nanoparticle is good and stable, we assume that the adsorptions of the gas molecules on the surface of the nanoparticle have a slight influence on the conductivity of the nanoparticle [1]. The main effect of the nanoparticle is the catalytic decomposition of some gas molecules [1]. We also calculated the adsorptions of SO₂, SOF₂, and SO₂F₂ on the Pt (200) surface to verify this finding. The adsorption structures are shown in Figure 18 [1]. In Figure 18a and b [1], we observed that SO₂ and SOF₂ form stable adsorption structures on the Pt (200) surface with the S atoms, which are similar to the structures on the single Pt atom of the anatase (101) surface. Figure 18c [1] is the stable adsorption structure of SO₂F₂ on the Pt (200) surface, which is different from the structure shown in Figure 17d [1], in that one

<table>
<thead>
<tr>
<th>Adsorption site</th>
<th>Structure</th>
<th>Adsorption energy</th>
<th>Charge transfer</th>
<th>Bond distance</th>
</tr>
</thead>
<tbody>
<tr>
<td>Adsorbed on the modified Pt atom</td>
<td>SO₂–TiO₂(a)</td>
<td>−0.2394</td>
<td>−0.115</td>
<td>2.329</td>
</tr>
<tr>
<td></td>
<td>SO₂–TiO₂(b)</td>
<td>−1.1009</td>
<td>−0.292</td>
<td>2.363</td>
</tr>
<tr>
<td></td>
<td>SOF₂–TiO₂(c)</td>
<td>−0.9416</td>
<td>−0.075</td>
<td>2.263</td>
</tr>
<tr>
<td></td>
<td>SO₂F₂–TiO₂(d)</td>
<td>−0.0630</td>
<td>0.020</td>
<td>2.425</td>
</tr>
</tbody>
</table>

**Table 6.** Adsorption parameters of the three gases adsorbed on the modified Pt atom of Pt-modified anatase.
Figure 17. TDOSs of the adsorption structures of $\text{SO}_2$, $\text{SOF}_2$, and $\text{SO}_2\text{F}_2$ on the modified Pt atom of Pt-modified anatase and PDOSs of the three gases in these structures.

**Figure 17. TDOSs of the adsorption structures of SO$_2$, SOF$_2$, and SO$_2$F$_2$ on the modified Pt atom of Pt-modified anatase and PDOSs of the three gases in these structures.**
S–F bond of SO₂F₂ breaks, as shown in Figure 18c [1], and SO₂F₂ is chemisorbed on the Pt (200) surface. The Pt (200) surface supplies more electrons than a single Pt atom of the anatase (101) surface and the S–F bond more easily breaks. Thus, we conclude that, when adsorbed on the Pt nanoparticles of the TNTA surface, the SO₂F₂ gas molecules are more easily catalytically decomposed by the Pt nanoparticles than the SOF₂ molecules.

Figure 19 [1] shows the adsorption structures of SO₂, SOF₂, and SO₂F₂ on Pt and anatase. The adsorption parameters are shown in Table 7 [1]. From Table 7 [1], we observed that the values of the adsorption energies of the three gases adsorbed on this site are relatively large, which indicates chemisorption [1]. The adsorption energy of SO₂F₂ is the largest and that of SOF₂ is the smallest. When SO₂ is adsorbed, the S atom of the SO₂ molecule bonds with the Pt atom, and one O atom of the SO₂ molecule bonds with the titanium (Ti) atom, as shown in Figure 19a [1]. When SOF₂ is adsorbed, the S atom of the SO₂ molecule also bonds with the Pt atom and one O atom of the SO₂ molecule bonds with the Ti atom, as shown in Figure 19b [1]. When SO₂F₂ is adsorbed, one S–F bond of SO₂F₂ breaks down. The S and F atoms bond with the Pt atom, with one O atom of the SO₂F₂ molecule bonding with the Ti atom, as shown in Figure 19c.

Figure 20 [1] shows the DOS of the three gases adsorbed on Pt and anatase. We observed that the adsorbed gas molecules contributed to the state density near the Fermi level, which also changes the electronic distribution of the area around this adsorption site. Considering the actual effect of Pt nanoparticles, we assume that this adsorption site is more active and the adsorptions of gas molecules on this site effectively connects the Pt nanoparticle surface and the anatase (101) surface, which may improve the conductivity performance of this area [1].

2.2.2. Preparation and surface characterization of Pt-doped TiO₂ nanotubes

The Pt-doped TiO₂NTs based on intrinsic TiO₂NTs were prepared using constant current method to deposit the Pt nanoparticles onto the TiO₂NT surface. Intrinsic TiO₂NTs were prepared through anodic oxidation [31], and a conventional three-electrode system with constant potential method is used to dope Pt nanoparticles into TiO₂NTs. In the three-electrode system, the intrinsic TiO₂NTs serve as the working electrode with a geometric area of 4.0 cm². The
Table 7. Adsorption parameters of the three gases adsorbed on both Pt and anatase.

<table>
<thead>
<tr>
<th>Adsorption site</th>
<th>Structure</th>
<th>Adsorption energy</th>
<th>Charge transfer</th>
<th>Bond distance</th>
</tr>
</thead>
<tbody>
<tr>
<td>Adsorbed on Pt and anatase</td>
<td>( \text{SO}_2\text{–Pt–TiO}_2) (a)</td>
<td>-1.4215</td>
<td>-0.2700</td>
<td>2.155</td>
</tr>
<tr>
<td></td>
<td>( \text{SOF}_2\text{–Pt–TiO}_2) (b)</td>
<td>-0.8405</td>
<td>-0.1930</td>
<td>2.273</td>
</tr>
<tr>
<td></td>
<td>( \text{SO}_2\text{F}_2\text{–Pt–TiO}_2) (c)</td>
<td>-1.6862</td>
<td>-0.7110</td>
<td>2.003</td>
</tr>
</tbody>
</table>

Figure 19. Adsorption structures of \( \text{SO}_2\), \( \text{SOF}_2\), and \( \text{SO}_2\text{F}_2\) on both Pt and anatase.

Figure 20. TDOSs of the adsorption structures of \( \text{SO}_2\), \( \text{SOF}_2\), and \( \text{SO}_2\text{F}_2\) on both Pt and anatase and PDOSs of the three gases in these structures.
Ag/AgCl electrode is the reference electrode, and platinum electrode functions as the counter electrode. An electronic pulse signal was produced in the constant current control mode of the Shanghai Chen Hua CHI660D electrochemical analyzer. The electrolyte was an aqueous solution of H$_2$PtCl$_6$·6H$_2$O (1 g/L) and H$_3$BO$_3$ (20 g/L) at 50°C (pH = 4.4). After numerous exploratory experiments, the optimal parameters determined for the constant current method are as follows: current density of 0.1 mA/cm$^2$, and doping times of 10, 20, 30, and 40 s. In the deposition process, a magnetic stirrer is used to ensure that the liquid has a stable metal ion concentration.

**Figure 21** shows the cyclic voltammetry curve of the four types of sensors with different amounts of doped Pt in 1.0 mol/L NaOH solution. Curves (a) to (d) correspond to the doping times of 10, 20, 30, and 40 s, respectively. During electrochemical deposition, Pt$^{4+}$ in the electrolyte is reduced to Pt, as described in [32]; the sizes of the curve areas were compared to determine the amount of deposited Pt metal. The humps between −1.0 and 0.8 V in the four curves shown in **Figure 21** correspond to the hydrogen absorption and dehydrogenation processes of the Pt ions in NaOH solution [33]. The hump in curve (a) is not evident, and the humps in curves (b) to (d) are significant. Based on the size of each curve surrounding the area, we concluded that the amount of deposited Pt nanoparticles on the TiO$_2$NT surface is proportional to deposition time.

**Figure 22** shows the SEM images of intrinsic and Pt-doped TiO$_2$NTs. **Figure 22a** shows the intrinsic TiO$_2$NTs, and **Figure 22b–e** presents the Pt-doped TiO$_2$NTs with deposition times of 10, 20, 30, and 40 s. The white objects around or above the tube wall in **Figure 22** are Pt nanoparticles. The SEM images show that the amount of Pt deposition increases with the deposition time. At 10 s, less Pt nanoparticles are deposited, and at 30 s, the Pt nanoparticles have moderate
sizes and are uniformly distributed. At 40 s, more Pt nanoparticles are deposited, and large tracts of these nanoparticles block the mouth of TiO$_2$NTs, as shown in Figure 22e.

Figure 23 shows that the intrinsic and Pt-doped TiO$_2$ NTs have strong anatase (101) crystal plane peak at 20 = 25.3° (A in Figure 23). Pt (111) and (200) crystal surface peaks at 20 = 40.5 and 46° were observed in the XRD patterns of the Pt-doped TiO$_2$ NTs.

However, no such peaks are found for the intrinsic TiO$_2$ NTs. This result shows that the constant potential method is useful when Pt nanoparticles are doped on TiO$_2$ NTs.
2.2.3. Gas-sensing experiments of Pt-doped TiO$_2$ nanotubes sensors

The performance of gas-sensitive metal oxide material is significantly influenced by working temperature. Therefore, the gas-sensing responses of the sensors with different amounts of doped Pt were investigated under different operating temperatures for SOF$_2$, SO$_2$F$_2$, and SO$_2$ gases. The optimal operating temperatures of the sensors were also determined.

The prepared Pt-doped sensors were placed into the test device (Figure 11). The sensor surface was then controllably heated. In this experiment, the sensor gas-sensing characteristics of the sensors for SOF$_2$, SO$_2$F$_2$, and SO$_2$ gases at 100 ppm from 20 to 220°C were examined. The results are shown in Figure 24.

Figure 24 shows the resistance sensitivity curves of the sensors with different amounts of doped Pt for SOF$_2$, SO$_2$F$_2$, and SO$_2$. The figure shows that the gas response value of the sensor (i.e., resistance change rate, $R\%$) increases with increasing sensor surface temperature. The optimal sensor operating temperature is approximately 160°C. When the temperature reaches 100–160°C, the largest response value is observed. As the temperature increases, the sensor response value begins to dramatically decrease. When the temperature reaches 200°C, the response value becomes small. The optimal operating temperatures and selectivity of the four sensors for the three decomposition component gases vary, as shown in Table 8.

The optimal operating temperature is 160, 150, 130, and 100°C at 10, 20, 30, and 40 s doping time, respectively. These results show that with increasing doping time, the optimal working
Figure 24. Sensitivity of sensors with different amounts of doped Pt with varying working temperatures.
temperature of the sensor decreases. In addition, at the optimal temperature, the sensor with 10 s of doping time is the most sensitive to SO$_2$ at −53.3% but has the weakest response to SO$_2$F$_2$ at −5.4%. The sensor with 20 s of doping time is most sensitive to SO$_2$ at −33.9% but has weakest response to SO$_2$F$_2$ at −19.2%. The sensor with 30 s of doping time is most sensitive to SO$_2$F$_2$ at −50.6% but has weakest response to SO$_2$ at −13.7%. The SOF$_2$ gas response values of these three sensors remained almost unchanged. The sensor with 40 s of doping of time has significantly low responses for the three gases.

Compared with the intrinsic TiO$_2$ NT sensor, the doped Pt nanoparticles alter the sensor surface microstructure and charge distribution. When the sensor surface temperature is higher than its optimum working temperature, the Pt nanoparticles improve the chemical desorption rate on the sensor surface. This result indicates that the desorption rate of a gas molecule is higher than its adsorption rate, and that the density of the gas molecule adsorbed onto the surface decreases, such that the response value of the sensor rapidly decreases. However, most parts of the tube mouth of the 40 s sensor are blocked by Pt nanoparticles; thus, the gas-sensing response value is highly reduced.

According to the experimental methods and procedures mentioned above, the four kinds of sensors function at their optimal operating temperatures. Their gas-sensing property curves are tested under SO$_2$, SOF$_2$, and SO$_2$F$_2$ gases at 25, 50, 75, and 100 ppm. The change rate of the sensor resistance (gas-sensing response value) was calculated at various concentrations. The linear relationship between the change rate of the sensor resistance and gas concentration was examined. Using the linear fit curve, we can also estimate the concentration of the gas using the sensor response value. After multiple experiments, the gas-sensing response values of the four sensors were found to increase with the experiment gas concentration, but for one kind of gas. Therefore, in the following section, only the 30 s sensor is considered, and its gas-sensing response curves were obtained at different gas concentrations. The experimental data of the remaining three sensors were obtained using the linear fit curve.

### Table 8. Sensitivity of Pt-doped sensors for 100 ppm SO$_2$, SOF$_2$, and SO$_2$F$_2$ at their optimum temperatures.

<table>
<thead>
<tr>
<th>Doping time</th>
<th>Optimal temperature</th>
<th>Sensitivity SO$_2$</th>
<th>Sensitivity SOF$_2$</th>
<th>Sensitivity SO$_2$F$_2$</th>
</tr>
</thead>
<tbody>
<tr>
<td>10 s</td>
<td>160°C</td>
<td>−53.3%</td>
<td>−24.2%</td>
<td>−5.4%</td>
</tr>
<tr>
<td>20 s</td>
<td>150°C</td>
<td>−33.9%</td>
<td>−22.1%</td>
<td>−19.2%</td>
</tr>
<tr>
<td>30 s</td>
<td>130°C</td>
<td>−13.8%</td>
<td>−19.1%</td>
<td>−50.6%</td>
</tr>
<tr>
<td>40 s</td>
<td>100°C</td>
<td>−6.7%</td>
<td>−5.1%</td>
<td>−10.7%</td>
</tr>
</tbody>
</table>

#### 2.2.3.1. Gas-sensing properties of sensors with different amounts of doped Pt to SO$_2$ gas

**Figure 25a** shows that sensor with 30 s of doping time has resistance change rates of −2.0, −7.0, −10.0, and −13.8% for the SO$_2$ gas at 25, 50, 75, and 100 ppm, respectively. **Figure 25b** shows that sensor with 10 s doping time has response values of −10.7, −25.6, −36.0, and −53.2% for the four SO$_2$ concentrations. For the sensor with 20 s of doping time, the response values
are −3.2, −13.4, −22.3, and −33.9% for the four SO\textsubscript{2} concentrations. Meanwhile, for the sensors with 40 s of doping time, response values are −0.8, −3.5, −5.0, and −6.7% for the four SO\textsubscript{2} concentrations. The sensitivities are shown in Table 9. The linear fit function and linear correlation coefficient are shown in Figure 25b.

<table>
<thead>
<tr>
<th>Concentration</th>
<th>SO\textsubscript{2}</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>10 s</td>
</tr>
<tr>
<td>100 ppm</td>
<td>−53.2%</td>
</tr>
<tr>
<td>75 ppm</td>
<td>−36.0%</td>
</tr>
<tr>
<td>50 ppm</td>
<td>−25.6%</td>
</tr>
<tr>
<td>25 ppm</td>
<td>−10.7%</td>
</tr>
</tbody>
</table>

**Table 9.** Sensitivity of Pt-doped 30 s sensor to different concentrations of SO\textsubscript{2} at optimal working temperature.

**Figure 25.** Response of four sensors with different amounts of doped Pt to varying concentrations of SO\textsubscript{2}. (a) Gas-sensing response curves of 30 s sensor for different concentrations of SO\textsubscript{2} gas at 130°C. (b) Linear relationship between sensor response and gas concentration.
2.2.3.2. Gas-sensing properties of sensors with different amounts of doped Pt for SO$_2$F$_2$ gas

**Figure 26a** shows the gas-sensing response curve of the sensor with 30 s doping time for SO$_2$F$_2$ at 25, 50, 75, and 100 ppm and 130°C. The resistance change rate is $-3.5$, $-16.1$, $-32.1$, and $-50.6\%$ for the different tested SO$_2$F$_2$ concentrations. **Figure 26b** shows that sensor with 10 s of doping time has response values of $-0.9$, $-2.1$, $-3.9$, and $-5.4\%$ for the different SO$_2$F$_2$ concentrations. The sensor with 20 s of doping time has response values of $-1.1$, $-7.8$, $-11.5$, and $-19.1\%$ for the different SO$_2$F$_2$ concentrations. The sensor with 40 s doping time has response values for $-0.9$, $-3.0$, $-7.2$, and $-10.9\%$ to the different SO$_2$F$_2$ concentrations. The sensor sensitivities are shown in **Table 10**. The linear fit function and linear correlation coefficient are shown in **Figure 26b**.

2.2.3.3. Gas-sensing properties of sensors with different amounts of doped Pt for SOF$_2$ gas

**Figure 27** shows that the sensor with 30 s of doping time has a resistance change rates of $-1.1$, $-6.3$, $-10.0$, and $-19.1\%$ for SOF$_2$ gas at 25, 50, 75, and 100 ppm, respectively. **Figure 27b** shows that the sensor with 10 s doping time has response values of $-3.2$, $-8.7$, $-15.8$, and $-24.9\%$ for the four SOF$_2$ concentrations. The sensor with 20 s doping time has response values of $-2.0$, $-8.2$, $-14.2$, and $-22.3\%$ for the four SOF$_2$ concentrations. The sensor with 40 s doping time has response values of $-0.8$, $-2.0$, $-3.9$, and $-5.3\%$ to four SOF$_2$ concentrations. The linear fit function and linear correlation coefficient are shown in **Figure 27b**.

**Figure 28** shows a comparison chart for the gas-sensing responses of the four sensors for SO$_2$, SOF$_2$, and SO$_2$F$_2$ gases at 100 ppm and at their optimal working temperatures. The responses of the intrinsic TiO$_2$NT sensor for these decomposition gases are discussed in Ref. [30]. With increasing doping amount, the sensor response for SO$_2$ decreases and follows the trend: intrinsic ($-73.5\%$) > 10 s ($-53.3\%$) > 20 s ($-33.9\%$) > 30 s ($-13.8\%$) > 40 s ($-6.7\%$). When the doping amount increases, the sensor response for SO$_2$F$_2$ increases and follows the trend: intrinsic ($-4.1\%$) < 10 s ($-5.4\%$) < 20 s ($-19.2\%$) < 30 s ($-50.6\%$) >> 40 s ($-10.9\%$). The responses of the 10, 20, and 30 s sensors for SOF$_2$ gas are nearly identical; however, response of the 40 s sensor for SOF$_2$ dramatically decreases.

**Figure 28** shows that the $R\%$ values of the Pt-doped TiO$_2$ nanotube for the three SF$_6$ decomposition gases are negative. This result indicates that the resistance of the Pt-doped TiO$_2$ nanotube sensor tends to decrease. Based on a known response mechanism, the three measured gases serve as reducing gases or as electron-donating gases. The reaction occurs as follows: $R + O_{ads}^{-} \rightarrow RO_{ads} + e^{-}$

where R is the SF$_6$ decomposition component gas (i.e., SO$_2$, SOF$_2$, and SO$_2$F$_2$), and O$_{ads}^{-}$ is the adsorbed oxygen ion on the sensor surface.

The results show that the reducing function and electron donating effect of SO$_2$ gas are the most prominent in the micro-oxidation reduction reaction (i.e., most likely to lose electrons). SO$_2$ is followed by SOF$_2$, while SO$_2$F$_2$ is the weakest. The selectivity of the sensor is highest for SO$_2$ gas. Therefore, the order of gas-sensing response of the intrinsic sensor for the three tested gases follows: SO$_2$ ($-74.6\%$) > SOF$_2$ ($-7.8\%$) > SO$_2$F$_2$ ($-5.5\%$) [34].
Figure 26. Response of four sensors with different amounts of doped Pt to varying concentrations of SO$_2$F$_2$. (a) Gas-sensing response curves of 30 s sensor for different concentrations of SO$_2$F$_2$ gas at 130°C. (b) Linear relationship between sensor response and gas concentration.

Table 10. Sensitivity of Pt-doped 30 s sensor to different concentrations of SO$_2$F$_2$ at optimal working temperature.

<table>
<thead>
<tr>
<th>Concentration</th>
<th>SO$_2$F$_2$</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>10 s</td>
</tr>
<tr>
<td>100 ppm</td>
<td>−5.4%</td>
</tr>
<tr>
<td>75 ppm</td>
<td>−3.8%</td>
</tr>
<tr>
<td>50 ppm</td>
<td>−2.1%</td>
</tr>
<tr>
<td>25 ppm</td>
<td>−0.9%</td>
</tr>
</tbody>
</table>
The doped Pt significantly affects the gas-sensing response of the TiO$_2$NT sensor for the SO$_2$, SOF$_2$, and SO$_2$F$_2$ gases, and thus, the selectivity of the sensor changes.

Pt serves as an oxygen storage point by constantly providing O$_{ads}^-$ to the TiO$_2$NT sensor surface. The noble metal doping specifically reduced the activation energy of the reaction O$_2$+2e$^-$$\rightarrow$2O$.^-$ Thus, the optimal working temperature also decreases, and the reaction rate and gas sensitive effects are enhanced. Meanwhile, the catalyst particles existing on the surface of the TiO$_2$-sensitive body has better affinity interactions with the target gases. Therefore, these gases will be more attached to the sensor surface at a lower temperature. The catalyst particles are embedded on the surface of the sensitive body. When the adhesion concentration of the measured gas on the catalyst particles surface reaches a certain value, these gases will “overflow” from the catalyst particles toward the surface of the sensitive body, and further react with the adsorbed oxygen ions. Ultimately, the sensitivity of this gas sensor increases, and the sensor response accelerates.

SO$_2$, SOF$_2$, and SO$_2$F$_2$ gases are specifically discussed. Sulfides have a certain degree of toxicity to noble metal catalysts, and the level of toxicity is associated with the valence elements and.

Figure 27. Responses of sensors doped with different amounts of Pt to varying concentrations of SOF$_2$. (a) Gas-sensing response curves of 30 s sensor for different concentrations SOF$_2$ gas at 130°C. (b) Linear relationship between sensor response and gas concentration.
molecular structure. The decreasing toxicity of the three experimental gases follows the order of $\text{SO}_2 > \text{SOF}_2 > \text{SO}_2\text{F}_2$; $\text{S}^{6+}$ within a certain range is non-toxic $[35]$. Therefore, once the strong toxicity of $\text{SO}_2$ accumulates, the Pt-doped sensor would be poisoned. The sensor poisoning follows a specific process. First, $\text{SO}_2$ is physically adsorbed on the active center of the catalyst, and then, redox reaction occurs between $\text{SO}_2$ and the active ingredient. Ultimately, the reaction produces alkylene sulfide and other sulfides, which block the active sites. In this complex series of processes, the activity of the catalyst decreases $[35]$; in addition, the sensitivity of the sensor is significantly improved with the nearly non-toxic $\text{SO}_2\text{F}_2$ gas.

2.3. Au-doped TiO$_2$ nanotubes

2.3.1. Investigation of gas-sensing simulation of Au-doped TiO$_2$ nanotubes

Intrinsic anatase TiO$_2$ (101) surface model was optimized in Dmol$^3$ module shown in Figure 29a, b while Au-doped anatase TiO$_2$ (101) surface model after optimization was exhibited in Figure 29c and d.

In Figure 30 $[1]$, density of states (DOS) of intrinsic and Au-doped anatase (101) surfaces as well as the doped Au atom was compared. As can be concluded, Au-doping could reduce band gap of TiO$_2$ to some extent $[1]$. To obtain more precise values, highest occupied molecular orbital (HOMO) and lowest unoccupied molecular orbital (LUMO) were calculated, and band gap of Au-doped anatase (101) surface was 1.906 eV, less than 1.932 eV, band gap of intrinsic anatase (101) surface $[1]$. The decrease of band gap made it easier for electrons to transfer from valence band to conduction band. In addition, Au-doping enhanced the DOS below Fermi level and increased density of electrons, providing more electrons which were possible to transfer to conduction band $[1]$. 

![Figure 28. Gas-sensing response of sensor with different amounts of doped Pt to SF$_6$ decomposition components.](image-url)
Gas molecules approach Au-doped anatase TiO$_2$ (101) surface by different atoms, shown in Figure 31. Considering structure features of SO$_2$F$_2$ that S atom is inside the tetrahedron made of O and F atoms, two conditions that SO$_2$F$_2$ approaches Au-doped anatase TiO$_2$ (101) surface by O and F atoms were taken into consideration. Table 11 [1] shows adsorption parameters of gases adsorbed on Au-doped anatase TiO$_2$ (101) surface. As can be found, when SO$_2$ molecule approaches Au atom by O or S atoms, adsorption parameters are close to each other, while similar condition occurs when SOF$_2$ approaches Au atom. When SO$_2$F$_2$ approaches Au atom by O atom, the adsorption energy and charge transfer are obviously smaller than those of the other condition that SO$_2$F$_2$ approaches Au atom by F atom, which indicates that it is easier for SO$_2$F$_2$ to adsorb on Au atom by F atom.

Figure 29. Views of intrinsic and Au-doped anatase TiO$_2$ (101) surface models from different angles.
By comparison of adsorption energy, it can be concluded that, whatever figure gas molecules approach adsorption surface by, adsorption energy of \( \text{SO}_2 \) is the largest, about 2–3 times that of \( \text{SOF}_2 \) and \( \text{SO}_2\text{F}_2 \) [1]. It can also be found from the view of charge transfer that, electrons transfer from adsorption surface to \( \text{SO}_2 \) molecule, the opposite direction of electron transfer in \( \text{SOF}_2 \) and \( \text{SO}_2\text{F}_2 \) adsorption processes [1]. The phenomenon can be explained by the strong oxidizing ability of \( \text{SO}_2 \). In addition, \( \text{SO}_2 \) adsorption possesses larger absolute value of charge transfer in adsorption process than \( \text{SOF}_2 \) and \( \text{SO}_2\text{F}_2 \) adsorption processes.

Figures 32–34 showed the total density of states (TDOS) of adsorption system and partial density of states (PDOS) of adsorbed gas molecules, \( \text{SO}_2 \), \( \text{SOF}_2 \), and \( \text{SO}_2\text{F}_2 \) respectively. “\( \text{SO}_2\text{-O-TiO}_2 \)” represents that \( \text{SO}_2 \) approaches anatase \( \text{TiO}_2 \) (101) surface by O atom, and the like.

In order to investigate the effect of Au-doping on gas-sensing properties of \( \text{TiO}_2 \) (101) surface, simulation results were compared with those of gas molecules adsorbed on intrinsic \( \text{TiO}_2 \) (101) surface [1]. Detailed calculation and results of adsorption on intrinsic \( \text{TiO}_2 \) (101) surface were included in the published reference [1, 36–39]. It should be noted that, in reference [32], \( \text{SO}_2 \) and \( \text{SOF}_2 \) molecules were adsorbed on intrinsic anatase \( \text{TiO}_2 \) (101) surface by O atom, while \( \text{SO}_2\text{F}_2 \) approached adsorption surface by F atom [1]. Therefore, the comparisons of adsorption parameters are mainly based on calculation results when gas molecules approached surface by the same atom [1]. In this paper, more approaching figures of gas molecules adsorbed on \( \text{TiO}_2 \) (101) surface are involved [1].

As can be concluded from the adsorption parameters, adsorption energy and charge transfer increased obviously after \( \text{SO}_2 \) molecule was adsorbed on Au-doped anatase \( \text{TiO}_2 \) (101) surface.
Figure 31. Adsorption structures of three gas molecules on Au-doped anatase TiO$_2$ (101) surface.
than intrinsic anatase TiO$_2$ (101) surface, while adsorption distance changed slightly [1]. More importantly, Au-doping changed the direction of charge transfer, causing the resistivity of adsorption system changing from decrease to increase [1]. As for SOF$_2$, adsorption energy increased by one-third while charge transfer and adsorption distance kept almost unchanged [1]. It can be judged that adsorption ability of SOF$_2$ on Au-doped surface slightly increased

<table>
<thead>
<tr>
<th>Gas molecules</th>
<th>Adsorption structure</th>
<th>Adsorption energy $E_a$/eV</th>
<th>Charge transfer $Q_e$/e</th>
<th>Adsorption distance $d$/Å</th>
</tr>
</thead>
<tbody>
<tr>
<td>SO$_2$</td>
<td>-S</td>
<td>-0.657</td>
<td>-0.156</td>
<td>2.601</td>
</tr>
<tr>
<td></td>
<td>-O</td>
<td>-0.571</td>
<td>-0.182</td>
<td>2.419</td>
</tr>
<tr>
<td>SOF$_2$</td>
<td>-S</td>
<td>-0.238</td>
<td>0.067</td>
<td>2.657</td>
</tr>
<tr>
<td></td>
<td>-O</td>
<td>-0.363</td>
<td>0.042</td>
<td>2.636</td>
</tr>
<tr>
<td></td>
<td>-F</td>
<td>-0.593</td>
<td>-0.006</td>
<td>2.656</td>
</tr>
<tr>
<td>SO$_2$F$_2$</td>
<td>-O</td>
<td>-0.071</td>
<td>0.009</td>
<td>2.667</td>
</tr>
<tr>
<td></td>
<td>-F</td>
<td>-0.200</td>
<td>0.039</td>
<td>2.924</td>
</tr>
</tbody>
</table>

Table 11. Adsorption parameters of gases adsorbed on Au-doped anatase TiO$_2$ (101) surface. “-S”, “-O” and “-F” represent that gas molecules approach adsorption surface by S, O and F atoms, respectively.

Figure 32. TDOS of adsorption systems and PDOS of adsorbed SO$_2$.
compared with that of SOF$_2$ on intrinsic surface [1]. After SO$_2$F$_2$ was adsorbed on Au-doped anatase TiO$_2$ (101) surface, adsorption distance became smaller, while adsorption energy and charge transfer became larger compared with the adsorption on intrinsic anatase TiO$_2$ (101) surface. It can also be found that absolute values of adsorption energy and charge transfer became larger when three molecules were adsorbed on Au-doped TiO$_2$ (101) surface with
adsorption distance almost unchanged compared with the adsorption on intrinsic surface. That is to say, Au-doping improved adsorption performance of intrinsic anatase TiO$_2$ (101) surface to SO$_2$, SOF$_2$, and SO$_2$F$_2$ [1]. When SO$_2$ molecule was adsorbed on Au-doped adsorption surface by S atom, adsorption energy was 0.657 > 0.6 eV, so the process belonged to chemical adsorption, while adsorption energy was 0.571 eV when SO$_2$ molecule was adsorbed by O atom, slightly smaller than 0.6 eV, which can be considered close to chemical adsorption. Adsorption energies of SOF$_2$ and SO$_2$F$_2$ molecules adsorbed on Au-doped adsorption surface were much smaller than 0.6 eV, belonging to physical adsorption [1].

TDOS of adsorption systems and gas molecules was compared, too [1]. Reference [41] shows TDOS of adsorption systems and PDOS of gas molecules adsorbed on intrinsic anatase TiO$_2$ (101) surface. By comparing with adsorption on intrinsic anatase TiO$_2$ (101) surface, an obvious TDOS peak did not appear above Fermi level when SO$_2$ was adsorbed on Au-doped anatase TiO$_2$ (101) surface [1]. As can be concluded, SO$_2$ molecule contributed less electrons to conduction band, leading to increase of adsorption system’s resistivity, which is consistent with the above analysis based on adsorption parameters. Au-doping changed variation tendency of adsorption system’s resistivity when SO$_2$ was adsorbed on anatase TiO$_2$ (101) surface [1].
Compared with adsorption of SOF₂ on intrinsic anatase TiO₂ (101) surface, SOF₂ made obvious contribution to DOS near Fermi level when it was adsorbed on Au-doped anatase TiO₂ (101) surface, which increased the amount of electrons in conduction band. From macroscopic view, resistivity of adsorption system dropped more severely and resistance declined more wildly as well in the adsorption process [1]. That is to say, Au-doping improved the sensitivity of anatase TiO₂ (101) surface to SOF₂ to some extent.

As far as SO₂F₂, adsorption of SO₂F₂ molecule did not contribute much to the DOS near Fermi level when SO₂F₂ was adsorbed on intrinsic anatase TiO₂ (101) surface, that is, SO₂F₂ provided almost no electrons for conduction band of adsorption system [1]. When SO₂F₂ was adsorbed on Au-doped anatase TiO₂ (101) surface, however, obvious DOS peaks appeared above Fermi level, and SO₂F₂ supplied more electrons to conduction band of adsorption system. Macroscopically, sensitivity of Au-doped anatase TiO₂ (101) surface to SO₂F₂ increased obviously compared with intrinsic anatase TiO₂ (101) surface [1].

Based on the above analysis of adsorption parameters and density of states, it can be concluded that, resistance’s variation tendency of Au-doped anatase TiO₂ (101) surface after the adsorption of SO₂ is decreasing, different from intrinsic anatase TiO₂ (101) surface [1]. Resistance of Au-doped anatase TiO₂ (101) surface dropped more, and the sensitivity increased slightly after SOF₂ adsorption, while resistance of Au-doped anatase TiO₂ (101) surface dropped severely, and the sensitivity increased obviously after SO₂F₂ adsorption [1].

2.3.2. Preparation and surface characterization of Au-doped TiO₂ nanotubes

To prepare the Au-TNTA, the intrinsic TiO₂ nanotubes were first fabricated, and then, Au was deposited onto the TiO₂ nanotubes using the deposition-precipitation method. The intrinsic TNTAs used in this paper were prepared by the anodic oxidation method [1, 38], and NaOH was selected as the precipitating agent. Firstly, the pH of the 1.01 × 10⁻³ mol/L HAuCl₄ solution was adjusted to 9 using NaOH solution [1]. Then, the intrinsic TiO₂ nanotubes were subsequently added to the above solution, resulting in the pH value decreasing. At the moment, a little more NaOH solution was needed to maintain the pH value at 9. Next, the resulting suspension was stirred for 2 h at 70°C to allow the Au to be supported on the carrier sufficiently. During the process, the suspension became pale purple gradually, and the pH value remained at 9 after cooling. TiO₂ nanotubes were picked out, washed, filtered, dried at room temperature and calcined for 4 h at 100°C to finally obtain the Au-TiO₂ nanotube sensors [1, 39].

As for the reasons for keeping the pH at 9, the selection of a pH value of 8–9 is in agreement with several previous experimental investigations [1, 40–45]. A number of groups have proven that the selection of pH leads to different geometries of TiO₂ [1, 45], and the pH of an aqueous solution dramatically affects the particle size of Au [1, 43]. Though a finite value for the size cannot be deduced from the activity, since the electronic factors depend on the interaction with the support, the morphology of the particle or the chemical state of the gold, there is general agreement that the activity increases as the particle size decreases [1, 44]. Hence, the pH value of the solution has significant influence on the catalytic activity.
A low pH causes a big Au particle, while a high pH causes a low Au deposition amount. The optimum pH aims to not only cause Au to be completely precipitated, but also leads to an appropriate diameter [1, 45]. Ivanova et al. have proven that when the pH value is above 8, the main species of Au in the solution is transformed from $\text{AuCl}_4^-$ to $\text{Au(OH)}_4^-$, leading to a smaller particle diameter. In order to remove $\text{Cl}^-$ ions completely [1, 46], we chose a pH of 9.

The sample morphology was analyzed by scanning electron microscopy (SEM). The SEM images were obtained by JEOLJSM7000 field emission SEM equipment operated at 10 kV [1].

*Figure 35* [1] shows SEM images of the pore size distribution of films composed of (a) intrinsic TiO$_2$ nanotubes and aggregates and (b) the Au nanoparticles distribution of Au-TiO$_2$ prepared by the deposition-precipitation method. The surfaces of the films were observed before and after Au deposition [1]. It is obvious that the morphology of the TiO$_2$ films is significantly changed after the Au nanoparticle modification. The adopted fabrication method results in the formation of tubular TiO$_2$ of 25 nm in diameter [1]. After the Au deposition treatment, the diameter of the tubes remains about the same. However, on the Au-TiO$_2$ surface, the pipes are covered with Au nanoparticles of a dozen nanometers in size, aggregating at the pipe orifices [1]. The SEM images confirm that the formed films, whether composed of intrinsic or Au-TiO$_2$, are homogeneous with a uniform distribution of pores or Au nanoparticles, respectively, as expected [1].

The crystal structures of the obtained intrinsic TiO$_2$ and Au-TiO$_2$ nanotubes were analyzed by X-ray diffraction, measured on an X’pert Pro (PANalytical, The Netherland) using Cu Kα radiation ($\lambda = 0.15405$ nm) at 40 kV, 35 mA. The wide-angle XRD patterns were collected at a scanning speed of 10°/min over the 2θ range of 20°–100°. *Figure 36* [1] gives the XRD patterns of the products prepared by the deposition-precipitation treatment. Previously, Varghese et al. observed both the anatase and rutile phases of TiO$_2$ by annealing treatment in ambient oxygen [1, 47, 48]. In our study, the labels A at 25.3° are observed in intrinsic, as well as in Au-doped
TiO$_2$, indicating that the crystal phases of TiO$_2$ are both anatase according to previous structural characterizations [1, 49], for which it can be confirmed that, in these preparation conditions, the TiO$_2$ nanotubes adopt an anatase crystal structure, while a rutile structure is not observed. The labels T and Au represent the reflections from the titanium substrate and different Au crystallographic forms. It is clearly seen from Figure 36 [1] that characteristic gold peaks come into existence in XRD analysis observed at 38.2° (111), 44.2° (200), 64.3° (220) and 98.1° (400), respectively. The main Au (111) characteristic peak suggests that approximately 10-nm gold nanoparticles are coated onto the anodized TiO$_2$ nanotubes on the basis of the Scherer formula [1, 50].

Meanwhile, a certain amount of 200, 220 and 400 Au particle crystal forms do exist [1]. There is a popular belief that the characteristics of a metal oxide semiconductor are greatly affected by the doped metal or metalloid, which would also influence the operating temperature in a sensing application further. Therefore, it is necessary to investigate the gas-sensing response of Au-TiO$_2$ NTAs to SF$_6$ decomposed components (i.e., 50 ppm SOF$_2$, SO$_2$F$_2$ and SO$_2$) in an operating range of 20–200°C in order to find out the optimum operating temperature [1].

2.3.3. Gas-sensing experiments of Au-doped TiO$_2$ nanotubes sensors

Figure 37 [1] depicts the curves of the resistance changes' rate (i.e., the response value) of Au-doped and intrinsic TiO$_2$ NTAs to SO$_2$, SOF$_2$, and SO$_2$F$_2$ at different operating temperatures. The response value of the intrinsic TiO$_2$ nanotubes to SF$_6$ decomposed components increases as the surface temperature rises, reaching saturation around 180°C, which is considered the optimum operating temperature. In the case of Au-TiO$_2$, the resistance response

![Figure 36. XRD of Au-TiO$_2$ nanotubes.](image-url)
increases with increasing operating temperature before 110°C, following the typical behavior of an oxide semiconductor [1]. However, the resistance response dramatically drops down when the temperature exceeds 110°C. Hence, the optimum operating temperature of the Au-TiO$_2$ nanotubes sensor is taken as 110°C. A comparison of Au-doped and intrinsic TiO$_2$ indicates that Au-doping reduces the working temperature of TiO$_2$ NTAs along with obvious changes in the temperature characteristic curve [1].

The performance of the intrinsic TiO$_2$ nanotube sensors maintaining its response value after it reaches 180°C might be attributed to the dynamic equilibrium of the gas adsorption and desorption rate on the sensor’s surface in the meantime [1]. As for Au-TiO$_2$, the Au nanoparticles change the microscopic structure and charge distribution of the surface, and the doped Au results in a promoted chemical desorption rate when the temperature surpasses 110°C, causing the oxygen desorption rate to be faster than its adsorption rate [1]. As a result, the oxygen chemisorption density on the surface decreases, leading to a rapid drop of the response value [1, 51].

The gas-sensing response curves of SO$_2$, SOF$_2$ and SO$_2$F$_2$ for Au-TiO$_2$ NTAs were recorded at different concentrations (i.e., 25, 50, 75, 100 ppm) under the optimal operating temperature (110°C) [1]. The results were linearly fit to investigate the linear relationship between the sensor’s resistance change and the gas concentration. Therefore, the concentration of target gases in real power equipment could be estimated through the linear relationship acquired by these sample gases [1].

**Figure 37.** Sensor responses for 50 ppm SO$_2$ (black dots), SOF$_2$ (red dots) and SO$_2$F$_2$ (green dots), respectively, for the intrinsic (short dashed lines, in the range of 20–240°C) and Au-doped TiO$_2$ (solid lines, in the range of 20–200°C) nanotubular films at different working temperatures.
2.3.3.1. Sensing performances of Au-TiO$_2$ NTAs for SO$_2$

As Figure 38 [1] shows, the resistance change rates of the Au-TiO$_2$ nanotube gas sensor for SO$_2$ at 25, 50, 75 and 100 ppm are −2.14, −8.73, −15.76 and −23.75%, respectively. The linear relationship between the sensor’s response value and the SO$_2$ concentration is evident in Figure 38 (b).

**Figure 38.** (a) Au-TiO$_2$ NTAs’ response to different concentrations of SO$_2$ at the 110°C working temperature. (b) Linear relationship between the sensor’s response value and the SO$_2$ concentration.
relationship between the sensor’s resistance change rate and the SO$_2$ concentration is fitted as $y = -0.287x + 5.37$ with a linear correlation coefficient ($R^2$) of 0.997 [1].

2.3.3.2. Sensing performances of Au-TiO$_2$ NTAs for SOF$_2$

Figure 39 [1] exhibits the sensing response curves of the Au-TiO$_2$ nanotube sensor for SOF$_2$ at different concentrations under 110°C. From Figure 39a, the resistance change rates that correspond to 25, 50, 75 and 100 ppm of SOF$_2$ are separately −3.00, −9.97, −18.42 and −28.37%. After linear fitting, the linear function is calculated to be $y = -0.338x + 6.197$, as shown in Figure 39b.

![Graph showing the response of Au-TiO$_2$ NTAs to SOF$_2$](image)

**Figure 39.** (a) Au-doped TiO$_2$ NTAs’ response to different concentrations of SOF$_2$ at the 110°C working temperature. (b) Linear relationship between the sensor’s response value and the SOF$_2$ concentration.
with $R^2$ equaling 0.991. It can be concluded that, within a certain range of concentrations, a linear relationship between the resistance change rate of the Au-TiO$_2$ nanotube sensor and the SOF$_2$ concentration is also displayed [1].

2.3.3.3. Sensing performances of Au-TiO$_2$ NTAs for SO$_2$F$_2$

Resistance change rates of Au-TiO$_2$ nanotube gas sensor for SOF$_2$ with different concentrations at 25, 50, 75 and 100 ppm are, respectively, −4.04, −19.58, −30.93 and −42.31%, as shown in Figure 40a. The linear fitting relationship is $y = -0.503x + 7.138$ and the linear correlation coefficient $R^2$ equals 0.991 [1].

![Figure 40a](image)

**Figure 40.** (a) Au-doped TiO$_2$ NTAs response to different concentrations of SO$_2$F$_2$ at the 110°C working temperature. (b) Linear relationship between the sensor's response value and the SO$_2$F$_2$ concentration.
Figure 41 [1] shows the gas-sensing response comparison chart of intrinsic and Au-doped TiO\textsubscript{2} NTAs at their optimum operating temperatures for 50 ppm SF\textsubscript{6} decomposed gases, that is, SO\textsubscript{2}, SOF\textsubscript{2} and SO\textsubscript{2}F\textsubscript{2}, where the gas-sensing properties of intrinsic TiO\textsubscript{2} NTAs have been discussed in [1, 52]. The responses of intrinsic and Au-doped TiO\textsubscript{2} NTAs both exhibit a negative behavior, that is, the resistances of intrinsic and Au-doped TiO\textsubscript{2} NTAs decrease after introducing these gases.

The gas-sensing response values of the intrinsic TiO\textsubscript{2} nanotube sensor are SO\textsubscript{2} (−74.6%) > SOF\textsubscript{2} (−7.82%) > SO\textsubscript{2}F\textsubscript{2} (−5.52%), while for the Au-TiO\textsubscript{2} nanotube sensor is SO\textsubscript{2}F\textsubscript{2} (−19.95%) > SOF\textsubscript{2} (−9.97%) > SO\textsubscript{2} (−8.73%). It is worth noting that the experimental results in our study are statistically significant, the values of which are at the average level according to dozens of experiments [1]. Obviously, the response value of SO\textsubscript{2}F\textsubscript{2} dramatically increases, while SO\textsubscript{2} is reduced, and the response of SOF\textsubscript{2} remains constant. The selective detection of SO\textsubscript{2}F\textsubscript{2} was actually achieved in our experimental research by the modification of Au nanoparticles at the appropriate operation temperature [1]. Hence, the Au-TiO\textsubscript{2} NTAs are potential substrates for the SO\textsubscript{2}F\textsubscript{2} detection application. Furthermore, combined Au-doped and intrinsic TiO\textsubscript{2} arrays are promising substrates for SF\textsubscript{6} decomposition component detection [1].

![Figure 41. Sensor responses of Au-doped and intrinsic TNTA for SF\textsubscript{6} decomposition components.](image)

Acknowledgements

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